

FEATURES

Ideally suited for automatic insertion

For Switching and AF Amplifier Applications

BC856A/B (PNP)
BC857A/B/C (PNP)
BC858A/B/C (PNP)

Marking

BC856A	BC856B	BC857A	BC857B
3A	3B	3E	3F
BC857C	BC858A	BC858B	BC858C
3G	3J	3K	3L

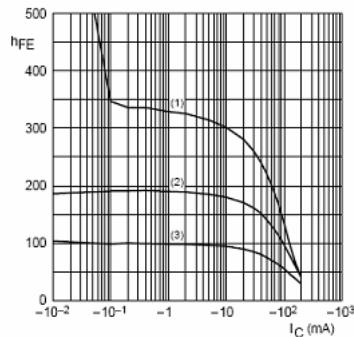


MAXIMUM RATINGS (TA=25°C unless otherwise noted)

Parameter		Symbol	Value	Unit
Collector-Base Voltage	BC856	V _{CBO}	-80	V
	BC857	V _{CBO}	-50	
	BC858	V _{CBO}	-30	
Collector-Emitter Voltage	BC856	V _{CEO}	-65	V
	BC857	V _{CEO}	-45	
	BC858	V _{CEO}	-30	
Emitter-Base Voltage		V _{EBO}	-5	V
Collector Current -Continuous		I _C	-0.1	A
Collector Power Dissipation		P _C	0.2	W
Junction Temperature		T _j	150	°C
Storage Temperature		T _{stg}	-55 to +150	°C

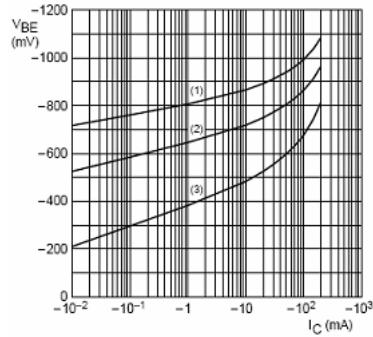
ELECTRICAL CHARACTERISTICS (T_{amb}=25°C unless otherwise specified)

Parameter		Symbol	Test conditions	Min	Max	Unit
Collector-base breakdown voltage	BC856	VCBO	I _C = -10μA, I _E =0	-80		
	BC857			-50		V
	BC858			-30		
Collector-emitter breakdown voltage	BC856	VCEO	I _C = -10mA, I _B =0	-65		
	BC857			-45		V
	BC858			-30		
Emitter-base breakdown voltage		VEBO	I _E = -1μA, I _C =0	-5		V
Collector cut-off current	BC856	I _{CBO}	V _{CB} = -70 V , I _E =0			
	BC857		V _{CB} = -45 V , I _E =0		-0.1	μA
	BC858		V _{CB} = -25 V , I _E =0			
Collector cut-off current	BC856	I _{CEO}	V _{CE} = -60 V , I _B =0			
	BC857		V _{CE} = -40 V , I _B =0		-0.1	μA
	BC858		V _{CE} = -25 V , I _B =0			
Emitter cut-off current		I _{EBO}	V _{EB} = -5 V , I _C =0		-0.1	μA
DC current gain	BC856A, 857A, 858A	h _{FE}	V _{CE} = -5V, I _C = -2mA	125	250	
	BC856B, 857B, 858B			220	475	
	BC857C, BC858C			420	800	
Collector-emitter saturation voltage		V _{CE(sat)}	I _C =-100mA, I _B = -5 mA		-0.5	V
Base-emitter saturation voltage		V _{BE(sat)}	I _C = -100mA, I _B = -5mA		-1.1	V
Transition frequency		f _T	V _{CE} = -5 V, I _C = -10mA f=100MHz	100		MHz
Collector capacitance		C _{ob}	V _{CB} =-10V, f=1MHz		4.5	pF

BC856A/B
BC857A/B/C Typical Characteristics
BC858A/B/C


BC857A; V_{CE} = -5 V.
(1) T_{amb} = 150 °C.
(2) T_{amb} = 25 °C.
(3) T_{amb} = -55 °C.

Fig.2 DC current gain as a function of collector current; typical values.



BC857A; V_{CE} = -5 V.
(1) T_{amb} = -55 °C.
(2) T_{amb} = 25 °C.
(3) T_{amb} = 150 °C.

Fig.3 Base-emitter voltage as a function of collector current; typical values.

BC856A/B BC857A/B/C Typical Characteristics BC858A/B/C

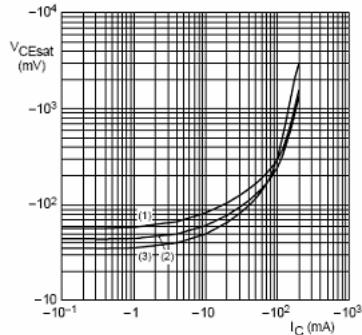
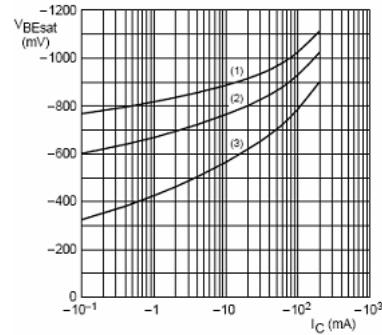
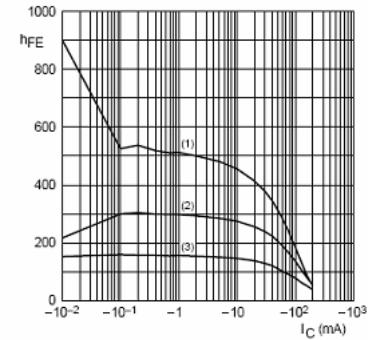


Fig.4 Collector-emitter saturation voltage as a function of collector current; typical values.
 BC857A; $I_C/I_B = 20$.
 (1) $T_{amb} = 150^\circ C$.
 (2) $T_{amb} = 25^\circ C$.
 (3) $T_{amb} = -55^\circ C$.



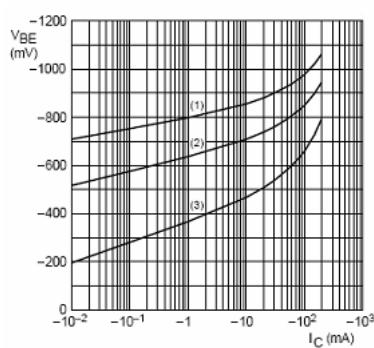
BC857A; $I_C/I_B = 20$.
 (1) $T_{amb} = 150^\circ C$.
 (2) $T_{amb} = 25^\circ C$.
 (3) $T_{amb} = -55^\circ C$.

Fig.5 Base-emitter saturation voltage as a function of collector current; typical values.

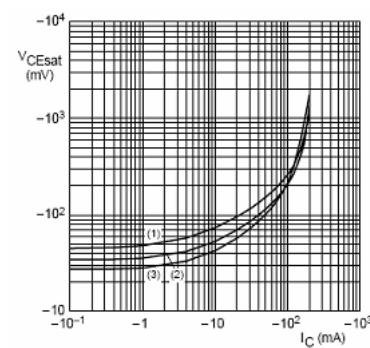


BC857B; $V_{CE} = -5$ V.
 (1) $T_{amb} = 150^\circ C$.
 (2) $T_{amb} = 25^\circ C$.
 (3) $T_{amb} = -55^\circ C$.

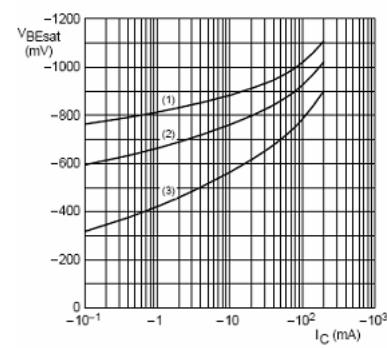
Fig.6 DC current gain as a function of collector current; typical values.



BC857B; $V_{CE} = -5$ V.
 (1) $T_{amb} = -55^\circ C$.
 (2) $T_{amb} = 25^\circ C$.
 (3) $T_{amb} = 150^\circ C$.



BC857B; $I_C/I_B = 20$.
 (1) $T_{amb} = 150^\circ C$.
 (2) $T_{amb} = 25^\circ C$.
 (3) $T_{amb} = -55^\circ C$.



BC857B; $I_C/I_B = 20$.
 (1) $T_{amb} = -55^\circ C$.
 (2) $T_{amb} = 25^\circ C$.
 (3) $T_{amb} = 150^\circ C$.